



2DD2652

LOW V_{CE(SAT)} NPN SURFACE MOUNT TRANSISTOR

Features

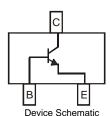
- Epitaxial Planar Die Construction
- Low Collector-Emitter Saturation Voltage
- Ideal for Low Power Amplification and Switching
- Complementary PNP Type Available (2DB1689)
- Ultra-Small Surface Mount Package
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green Device" (Note 2)

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe.
 Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.006 grams (approximate)







Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	15	V
Collector-Emitter Voltage	V _{CEO}	12	V
Emitter-Base Voltage	V_{EBO}	6	V
Collector Current - Continuous	Ic	1.5	Α
Peak Pulse Collector Current	I _{CM}	3	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ T _A = 25°C	PD	300	mW
Thermal Resistance, Junction to Ambient (Note 3) @ T _A = 25°C	$R_{ heta JA}$	417	°C/W
Power Dissipation (Note 4) @ T _A = 25°C	PD	500	mW
Thermal Resistance, Junction to Ambient (Note 4) @ T _A = 25°C	$R_{ heta JA}$	250	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Conditions
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	V _{(BR)CBO}	15	_	_	V	$I_C = 10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage (Note 5)	V _{(BR)CEO}	12	_	_	V	$I_{C} = 1 \text{mA}, I_{B} = 0$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	6	_	_	V	$I_E = 10\mu A, I_C = 0$
Collector Cut-Off Current	I _{CBO}	_	_	0.1	μΑ	V _{CB} = 15V, I _E = 0
Emitter Cut-Off Current	I _{EBO}	_	_	0.1	μΑ	$V_{EB} = 6V, I_{C} = 0$
ON CHARACTERISTICS (Note 5)						•
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	80	200	mV	$I_C = 500 \text{mA}, I_B = 25 \text{mA}$
DC Current Gain	h _{FE}	270	_	680	_	$V_{CE} = 2V, I_{C} = 200mA$
SMALL SIGNAL CHARACTERISTICS						_
Output Capacitance	C _{obo}	_	11	_	pF	$V_{CB} = 10V, I_{E} = 0,$ f = 1MHz
Current Gain-Bandwidth Product	f _T	_	260	_	MHz	V _{CE} = 2V, I _C = 100mA, f = 100MHz

Notes:

- 1. No purposefully added lead.
- 2. Diode's Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 3. Device mounted on FR-4 PCB with minimum recommended pad layout.
- Device mounted on FR-4 PCB with 1 inch² copper pad layout.
- Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤2%.



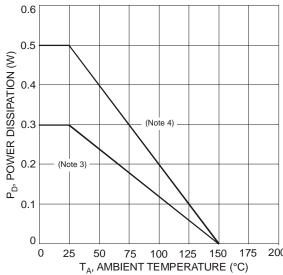


Fig. 1 Power Dissipation vs. Ambient Temperature

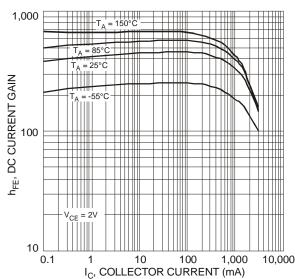
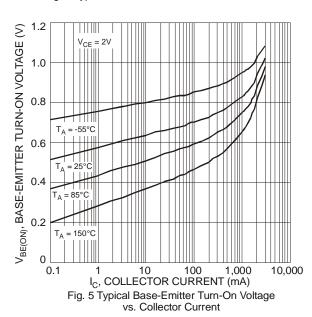


Fig. 3 Typical DC Current Gain vs. Collector Current



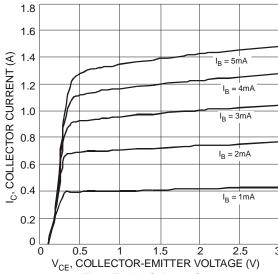


Fig. 2 Typical Collector Current vs. Collector-Emitter Voltage

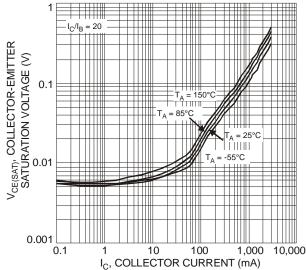


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

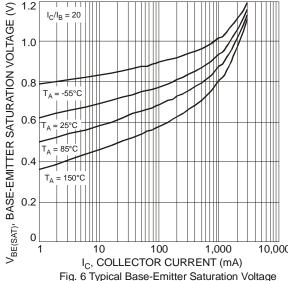
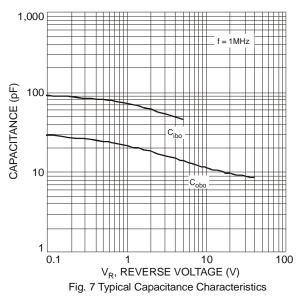


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current



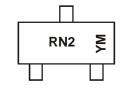


Ordering Information (Note 6)

Part Number	Case	Packaging
2DD2652-7	SOT-323	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

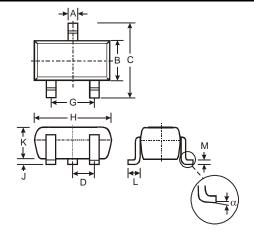


RN2 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: V = 2008) M = Month (ex: 9 = September)

Date Code Key

Year	2008		2009	2010		2011	2012		2013	2014		2015
Code	V		W	X		Υ	Z		Α	В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

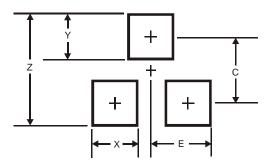
Package Outline Dimensions



SOT-323					
Dim	Min	Max	Тур		
Α	0.25	0.40	0.30		
В	1.15	1.35	1.30		
C	2.00	2.20	2.10		
D	-	-	0.65		
G	1.20	1.40	1.30		
Ι	1.80	2.20	2.15		
7	0.0	0.10	0.05		
K	0.90	1.00	1.00		
L	0.25	0.40	0.30		
М	0.10	0.18	0.11		
α	0°	8°	-		
All Dimensions in mm					



Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Υ	0.9
С	1.9
E	1.0

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